

SN54ABT861, SN74ABT861 10-BIT TRANSCEIVERS WITH 3-STATE OUTPUTS

SCBS199C – FEBRUARY 1991 – REVISED MAY 1997

- State-of-the-Art *EPIC-II B*™ BiCMOS Design Significantly Reduces Power Dissipation
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- High-Impedance State During Power Up and Power Down
- Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17
- High-Drive Outputs (–32-mA I_{OH} , 64-mA I_{OL})
- Package Options Include Plastic Small-Outline (DW) Package, Ceramic Chip Carriers (FK), and Plastic (NT) and Ceramic (JT) DIPs

description

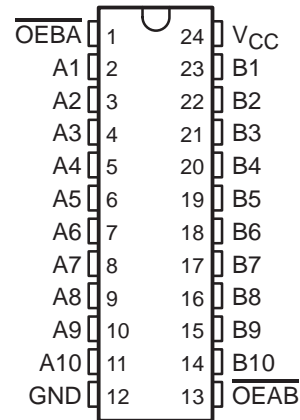
The 'ABT861 are 10-bit transceivers designed for asynchronous communication between data buses. The control-function implementation allows for maximum flexibility in timing.

These devices allow noninverted data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic levels at the output-enable (\overline{OEAB} and \overline{OEBA}) inputs.

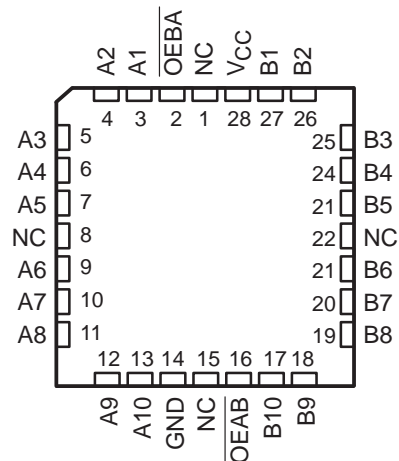
When V_{CC} is between 0 and 2.1 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 2.1 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54ABT861 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ABT861 is characterized for operation from –40°C to 85°C.

SN54ABT861 . . . JT PACKAGE
SN74ABT861 . . . DW OR NT PACKAGE
(TOP VIEW)



SN54ABT861 . . . FK PACKAGE
(TOP VIEW)



NC – No internal connection



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UNLESS OTHERWISE NOTED this document contains PRODUCTION DATA information current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

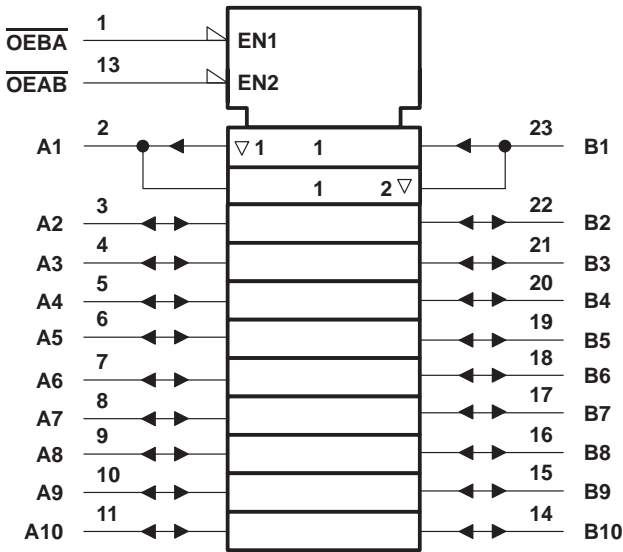
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FUNCTION TABLE

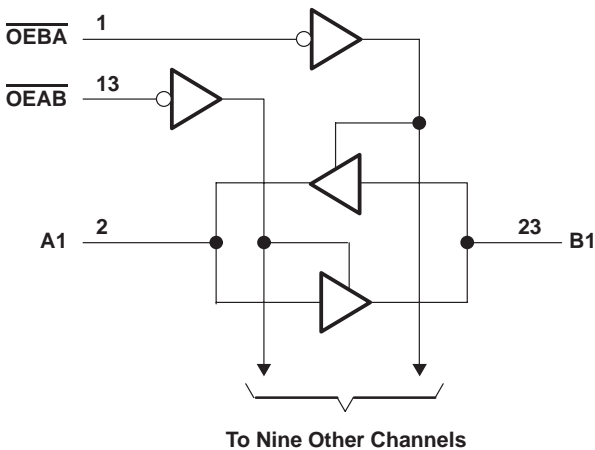
INPUTS		OPERATION
\overline{OEAB}	\overline{OEBA}	
L	H	A data to B bus
H	L	B data to A bus
H	H	Isolation
L	L	Latch A and B (A = B)

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for the DW, JT, and NT packages.

logic diagram (positive logic)



Pin numbers shown are for the DW, JT, and NT packages.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC}	–0.5 V to 7 V
Input voltage range, V_I (except I/O ports) (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high or power-off state, V_O	–0.5 V to 5.5 V
Current into any output in the low state, I_O : SN54ABT861	96 mA
SN74ABT861	128 mA
Input clamp current, I_{IK} ($V_I < 0$)	–18 mA
Output clamp current, I_{OK} ($V_O < 0$)	–50 mA
Package thermal impedance, θ_{JA} (see Note 2): DW package	81°C/W
NT package	67°C/W
Storage temperature range, T_{stg}	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. The package thermal impedance is calculated in accordance with EIA/JEDEC Std JESD51, except for through-hole packages, which use a trace length of zero.

recommended operating conditions (see Note 3)

		SN54ABT861		SN74ABT861		UNIT
		MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage	4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage	2		2		V
V_{IL}	Low-level input voltage		0.8		0.8	V
V_I	Input voltage	0	V_{CC}	0	V_{CC}	V
I_{OH}	High-level output current		–24		–32	mA
I_{OL}	Low-level output current		48		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled		5	5	ns/V
T_A	Operating free-air temperature	–55	125	–40	85	°C

NOTE 3: Unused pins (input or I/O) must be held high or low to prevent them from floating.

SN54ABT861, SN74ABT861

10-BIT TRANSCEIVERS

WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A = 25°C			SN54ABT861		SN74ABT861		UNIT	
				MIN	TYP†	MAX	MIN	MAX	MIN	MAX		
V _{IK}		V _{CC} = 4.5 V, I _I = -18 mA		-1.2			-1.2		-1.2		V	
V _{OH}		V _{CC} = 4.5 V, I _{OH} = -3 mA		2.5			2.5		2.5		V	
		V _{CC} = 5 V, I _{OH} = -3 mA		3			3		3			
		V _{CC} = 4.5 V		I _{OH} = -24 mA			2					
				I _{OH} = -32 mA			2*			2		
V _{OL}		V _{CC} = 4.5 V		I _{OL} = 48 mA			0.55					V
				I _{OL} = 64 mA			0.55*			0.55		
V _{hys}				100							mV	
I _I	Control inputs	V _{CC} = 5.5 V, V _I = V _{CC} or GND		±1			±1		±1		μA	
	A or B ports			±100			±100		±100			
I _{OZPU} ‡		V _{CC} = 0 to 2.1 V, V _O = 0.5 V to 2.7 V, OE = X		±50			±50		±50		μA	
I _{OZPD} ‡		V _{CC} = 2.1 V to 0, V _O = 0.5 V to 2.7 V, OE = X		±50			±50		±50		μA	
I _{OZH} §		V _{CC} = 5.5 V, V _O = 2.7 V		50			50		50		μA	
I _{OZL} §		V _{CC} = 5.5 V, V _O = 0.5 V		-50			-50		-50		μA	
I _{off}		V _{CC} = 0, V _I or V _O ≤ 4.5 V		±100					±100		μA	
I _{CEX}		V _{CC} = 5.5 V, V _O = 5.5 V		50			50		50		μA	
I _O ¶		V _{CC} = 5.5 V, V _O = 2.5 V		-50	-100	-225#	-50	-225#	-50	-225#	mA	
I _{CC}	A or B ports	V _{CC} = 5.5 V, I _O = 0, V _I = V _{CC} or GND		Outputs high		1	250	250		250		μA
				Outputs low		24	38	38		38		mA
				Outputs disabled		0.5	250	250		250		μA
ΔI _{CC}	Data inputs	V _{CC} = 5.5 V, One input at 3.4 V, Other inputs at V _{CC} or GND		Outputs enabled		1.5		1.5		1.5		mA
				Outputs disabled		1.5#		1.5#		1.5#		
	Control inputs	V _{CC} = 5.5 V, One input at 3.4 V, Other inputs at V _{CC} or GND		1.5			1.5		1.5			
C _i	Control inputs	V _I = 2.5 V or 0.5 V		4.5							pF	
C _{io}	A or B ports	V _O = 2.5 V or 0.5 V		10.5							pF	

* On products compliant to MIL-PRF-38535, this parameter does not apply.

† All typical values are at V_{CC} = 5 V.

‡ This parameter is characterized, but not production tested.

§ The parameters I_{OZH} and I_{OZL} include the input leakage current.

¶ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

This limit may vary among suppliers.

|| This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

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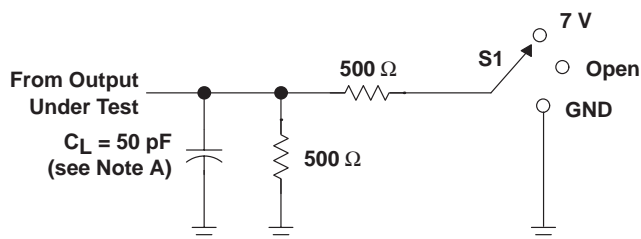
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switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50$ pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 5$ V, $T_A = 25^\circ\text{C}$			SN54ABT861		SN74ABT861		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A or B	B or A	1	3.4	4.9	1	5.3	1	5.2	ns
t_{PHL}			1	3.2	4.4	1	5	1	4.9†	
t_{PZH}	\overline{OEAB} or \overline{OEBA}	B or A	1	3.5	5	1	6	1	5.9	ns
t_{PZL}			1	4.6	6	1	7	1	6.9	
t_{PHZ}	\overline{OEAB} or \overline{OEBA}	B or A	2.1	5.3	6.5	2.1	7.6	2.1	7.5	ns
t_{PLZ}			1.5	5.3	6.6	1.5	7.2	1.5	7.1	

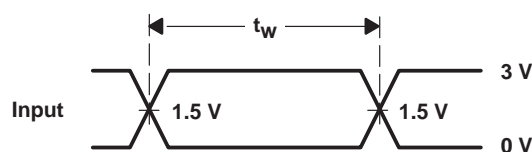
† This limit may vary among suppliers.

PARAMETER MEASUREMENT INFORMATION

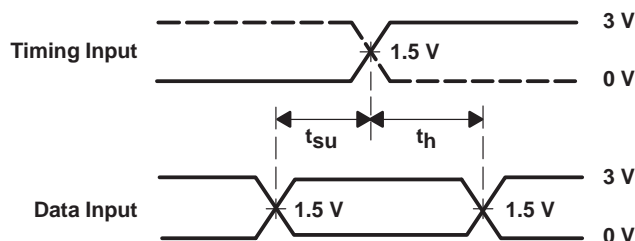


LOAD CIRCUIT

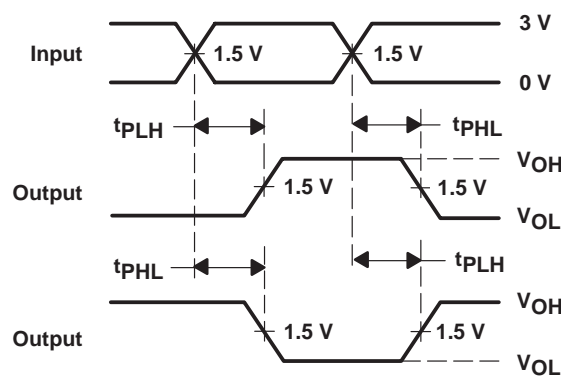
TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	7 V
t_{PHZ}/t_{PZH}	Open



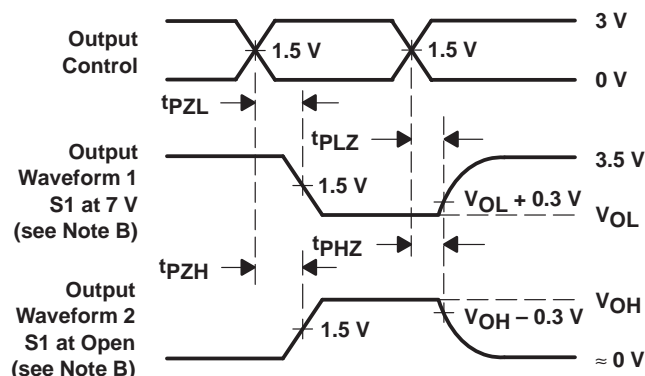
VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

- NOTES:
- C_L includes probe and jig capacitance.
 - Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r \leq 2.5 \text{ ns}$, $t_f \leq 2.5 \text{ ns}$.
 - The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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